

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

10/525244

In re the Application of  
Ryoji HOSHI et al.

DT01 Rec'd PCT/PTO 22 FEB 2005

Application No.: New U.S. National Stage of PCT/JP03/11443

Filed: February 22, 2005

Docket No.: 122810

For: SINGLE CRYSTAL, SINGLE CRYSTAL WAFER, EPITAXIAL WAFER, AND METHOD  
OF GROWING SINGLE CRYSTAL

INFORMATION DISCLOSURE STATEMENT


Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

Pursuant to 37 CFR §1.56, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached PTO-1449. Unless otherwise indicated herein, one copy of each reference is attached. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

- ☒ 1. This Information Disclosure Statement is being filed (a) within three months of the U.S. filing date of this non-CPA application, OR (b) before the mailing date of a first Office Action on the merits in the present application. No certification or fee is required.
- ☒ 2. Relevance of reference 5 is discussed in the present specification.
- ☒ 3. The references were cited in the International Search Report. An English language version of the International Search Report is attached for the Examiner's information.
- ☒ 4. In accordance with 37 CFR §1.98(a)(2)(ii), copies of any U.S. patents and patent application publications are not attached.
- ☒ 5. English language Abstracts of the non-English language references are attached hereto.
- ☒ 6. Computer-generated English language translations of the following Japanese references have been obtained from the website of the Japanese Patent Office ([<http://www.jpo.go.jp>]), and are attached, but have not been reviewed for accuracy. See References 3-5.

Respectfully submitted,

  
William P. Berridge  
Registration No. 30,024

Eric D. Morehouse  
Registration No. 38,565

WPB:EDM/nxy

Date: February 22, 2005

OLIFF & BERRIDGE, PLC  
P.O. Box 19928  
Alexandria, Virginia 22320  
Telephone: (703) 836-6400

DEPOSIT ACCOUNT USE AUTHORIZATION Please grant any extension necessary for entry; Charge any fee due to our Deposit Account No. 15-0461
--

Form PTO-1449 (REV. 8-83)		US Dept. of Commerce PATENT & TRADEMARK OFFICE		ATTY DOCKET NO. 122810		APPLICATION NO. New U.S. National Stage of PCT/JP03/11443 <b>10/52524</b>	
INFORMATION DISCLOSURE STATEMENT  (Use several sheets if necessary)				APPLICANTS Ryoji HOSHI et al.			
				FILING DATE February 22, 2005			

U.S. PATENT DOCUMENTS						
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS
	1.	6,200,384 B1	03/13/2001	Yutaka KISHIDA et al.		

FOREIGN PATENT DOCUMENTS						
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS
	2.	WO 02/10485 A1 w/ abst.	02/07/2002	WIPO		
	3.	JP-A-2001-326228 w/ abst. & trans.	11/22/2001	JAPAN		
	4.	JP-A-2001-127016 w/ abst. & trans.	05/11/2001	JAPAN		
	5.	JP-A-2002-141311 w/ abst. & trans.	05/17/2002	JAPAN		

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)						

EXAMINER	DATE CONSIDERED
Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	

Date: February 22, 2005